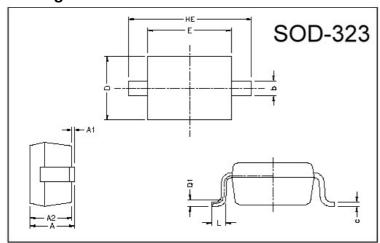
GD1SS355

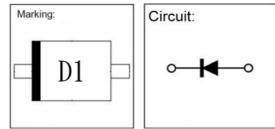
SURFACE MOUNT, SWITCHING DIODE **VOLTAGE 90V, CURRENT 0.1A**

Description

The GD1SS355 is designed for ultra high speed switching and high reliability with high surge current handling capability.

Package Dimensions





REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	NEF.	Min.	Max.
Α	0.85	1.05			
A1	0	0.10	L	0.20	0.40
A2	0.80	1.00	b	0.25	0.40
D	1.15	1.45	С	0.10	0.18
E	1.60	1.80			
HE	2.30	2.70	Q1	0.15 BSC.	

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Ratings	Unit
Junction Temperature	Tj	+125	°C
Storage Temperature	Tstg	-55 ~ +125	°C
Maximum Peak Repetitive Reverse Voltage	V _{RRM}	90	V
Maximum RMS Voltage	V _{RMS}	63	V
Maximum DC Blocking Voltage	V _{DC}	80	V
Peak Forward Surge Current at 8.3mSec single half sine-wave	I _{FSM}	0.5	A
Typical Junction Capacitance between Terminal (Note 1)	CJ	3.0	pF
Maximum Reverse Recovery Time (Note2)	T _{RR}	4.0	nSec
Maximum Average Forward Rectified Current	lo	0.1	A
Total Power Dissipation	PD	225	mW

Characteristics at Ta = 25°C

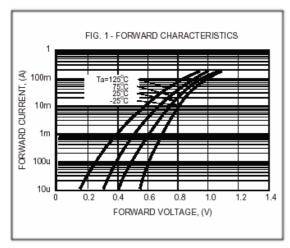
Characteristics	Symbol	Max	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V_{F}	1.20	V	IF = 100mA
Maximum Average Reverse Current	IR	0.1	uA	VR = 80V

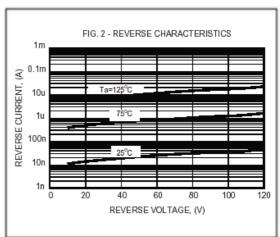
Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 6.0 volt.

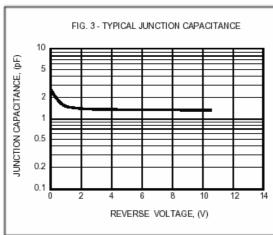
- 2. Measured at applied forward current of 10mA and reverse voltage of 6.0 volt.
- 3. ESD sensitive product handling required.

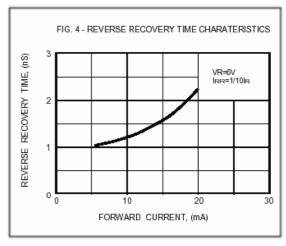
GD1SS355 Page: 1/2

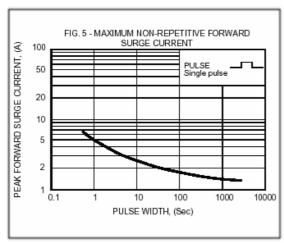
Characteristics Curve

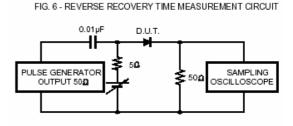












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